

# BIPOLAR ANALOG INTEGRATED CIRCUIT

# $\mu$ PC3232TB

## 5 V, SILICON GERMANIUM MMIC

## MEDIUM OUTPUT POWER AMPLIFIER

### DESCRIPTION

The  $\mu$ PC3232TB is a silicon germanium (SiGe) monolithic integrated circuit designed as IF amplifier for DBS tuners. This IC is manufactured using our 50 GHz  $f_{\max}$  UHS2 (Ultra High Speed Process) SiGe bipolar process.

### FEATURES

- Low current :  $I_{CC} = 26.0$  mA TYP.
- Medium output power :  $P_{O(sat)} = +15.5$  dBm TYP. @  $f = 1.0$  GHz  
:  $P_{O(sat)} = +12.0$  dBm TYP. @  $f = 2.2$  GHz
- High linearity :  $P_{O(1\text{ dB})} = +11.0$  dBm TYP. @  $f = 1.0$  GHz  
:  $P_{O(1\text{ dB})} = +8.5$  dBm TYP. @  $f = 2.2$  GHz
- Power gain :  $G_P = 32.8$  dB MIN. @  $f = 1.0$  GHz  
:  $G_P = 33.5$  dB MIN. @  $f = 2.2$  GHz
- Gain flatness :  $\Delta G_P = 1.0$  dB TYP. @  $f = 1.0$  to  $2.2$  GHz
- Noise figure :  $NF = 4$  dB TYP. @  $f = 1.0$  GHz  
:  $NF = 4.1$  dB TYP. @  $f = 2.2$  GHz
- Supply voltage :  $V_{CC} = 4.5$  to  $5.5$  V
- Port impedance : input/output  $50\ \Omega$

### APPLICATIONS

- IF amplifiers in LNB for DBS converters etc.

### ORDERING INFORMATION

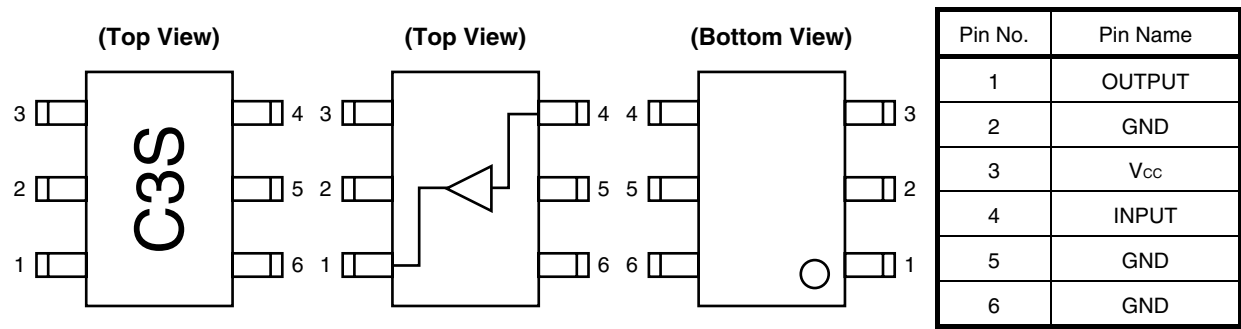
| Part Number       | Order Number        | Package                        | Marking | Supplying Form                                                                                                                                                      |
|-------------------|---------------------|--------------------------------|---------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $\mu$ PC3232TB-E3 | $\mu$ PC3232TB-E3-A | 6-pin super minimold (Pb-Free) | C3S     | <ul style="list-style-type: none"> <li>• Embossed tape 8 mm wide</li> <li>• Pin 1, 2, 3 face the perforation side of the tape</li> <li>• Qty 3 kpcs/reel</li> </ul> |

**Remark** To order evaluation samples, please contact your nearby sales office  
Part number for sample order:  $\mu$ PC3232TB

**Caution** Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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PIN CONNECTIONS



PRODUCT LINE-UP OF 5 V-BIAS SILICON MMIC MEDIUM OUTPUT POWER AMPLIFIER  
(T<sub>A</sub> = +25°C, f = 1 GHz, V<sub>CC</sub> = V<sub>out</sub> = 5.0 V, Z<sub>S</sub> = Z<sub>L</sub> = 50 Ω)

| Part No.       | P <sub>O (sat)</sub><br>(dBm) | G <sub>P</sub><br>(dB) | NF<br>(dB)          | I <sub>CC</sub><br>(mA) | Package              | Marking |
|----------------|-------------------------------|------------------------|---------------------|-------------------------|----------------------|---------|
| $\mu$ PC2708TB | +10.0                         | 15.0                   | 6.5                 | 26                      | 6-pin super minimold | C1D     |
| $\mu$ PC2709TB | +11.5                         | 23.0                   | 5.0                 | 25                      |                      | C1E     |
| $\mu$ PC2710TB | +13.5                         | 33.0                   | 3.5                 | 22                      |                      | C1F     |
| $\mu$ PC2776TB | +8.5                          | 23.0                   | 6.0                 | 25                      |                      | C2L     |
| $\mu$ PC3223TB | +12.0                         | 23.0                   | 4.5                 | 19                      |                      | C3J     |
| $\mu$ PC3225TB | +15.5 <sup>Note</sup>         | 32.5 <sup>Note</sup>   | 3.7 <sup>Note</sup> | 24.5                    |                      | C3M     |
| $\mu$ PC3226TB | +13.0                         | 25.0                   | 5.3                 | 15.5                    |                      | C3N     |
| $\mu$ PC3232TB | +15.5                         | 32.8                   | 4.0                 | 26                      |                      | C3S     |

**Note**  $\mu$ PC3225TB is f = 0.95 GHz

**Remark** Typical performance. Please refer to **ELECTRICAL CHARACTERISTICS** in detail.

# ABSOLUTE MAXIMUM RATINGS

| Parameter                     | Symbol           | Conditions                         | Ratings     | Unit |
|-------------------------------|------------------|------------------------------------|-------------|------|
| Supply Voltage                | V <sub>CC</sub>  | T <sub>A</sub> = +25°C             | 6.0         | V    |
| Total Circuit Current         | I <sub>CC</sub>  | T <sub>A</sub> = +25°C             | 45          | mA   |
| Power Dissipation             | P <sub>D</sub>   | T <sub>A</sub> = +85°C <b>Note</b> | 270         | mW   |
| Operating Ambient Temperature | T <sub>A</sub>   |                                    | −40 to +85  | °C   |
| Storage Temperature           | T <sub>stg</sub> |                                    | −55 to +150 | °C   |
| Input Power                   | P <sub>in</sub>  | T <sub>A</sub> = +25°C             | 0           | dBm  |

**Note** Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

# RECOMMENDED OPERATING RANGE

| Parameter                     | Symbol          | Conditions | MIN. | TYP. | MAX. | Unit |
|-------------------------------|-----------------|------------|------|------|------|------|
| Supply Voltage                | V <sub>CC</sub> |            | 4.5  | 5.0  | 5.5  | V    |
| Operating Ambient Temperature | T <sub>A</sub>  |            | −40  | +25  | +85  | °C   |

**ELECTRICAL CHARACTERISTICS** ( $T_A = +25^\circ\text{C}$ ,  $V_{CC} = V_{out} = 5.0\text{ V}$ ,  $Z_S = Z_L = 50\ \Omega$ )

| Parameter                                     | Symbol                | Test Conditions                                                                            | MIN. | TYP.  | MAX. | Unit |
|-----------------------------------------------|-----------------------|--------------------------------------------------------------------------------------------|------|-------|------|------|
| Circuit Current                               | $I_{CC}$              | No input signal                                                                            | 20   | 26    | 32   | mA   |
| Power Gain 1                                  | $G_{P1}$              | $f = 0.25\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                          | 29   | 31.5  | 34   | dB   |
| Power Gain 2                                  | $G_{P2}$              | $f = 1.0\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 30   | 32.8  | 35.5 |      |
| Power Gain 3                                  | $G_{P3}$              | $f = 1.8\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 31   | 33.8  | 37   |      |
| Power Gain 4                                  | $G_{P4}$              | $f = 2.2\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 30.5 | 33.5  | 36.5 |      |
| Power Gain 5                                  | $G_{P5}$              | $f = 2.6\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 29   | 32.2  | 35.5 |      |
| Power Gain 6                                  | $G_{P6}$              | $f = 3.0\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 27   | 30.7  | 34   |      |
| Gain Flatness                                 | $\Delta G_P$          | $f = 1.0\text{ to }2.2\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                             | —    | 1.0   | —    | dB   |
| K factor 1                                    | K1                    | $f = 1.0\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | —    | 1.3   | —    | —    |
| K factor 2                                    | K2                    | $f = 2.2\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | —    | 1.9   | —    | —    |
| Saturated Output Power 1                      | $P_{O(sat)1}$         | $f = 1.0\text{ GHz}$ , $P_{in} = 0\text{ dBm}$                                             | +13  | +15.5 | —    | dBm  |
| Saturated Output Power 2                      | $P_{O(sat)2}$         | $f = 2.2\text{ GHz}$ , $P_{in} = -5\text{ dBm}$                                            | +9.5 | +12   | —    |      |
| Gain 1 dB Compression Output Power 1          | $P_{O(1\text{ dB})1}$ | $f = 1.0\text{ GHz}$                                                                       | +8   | +11   | —    | dBm  |
| Gain 1 dB Compression Output Power 2          | $P_{O(1\text{ dB})2}$ | $f = 2.2\text{ GHz}$                                                                       | +6   | +8.5  | —    |      |
| Noise Figure 1                                | NF1                   | $f = 1.0\text{ GHz}$                                                                       | —    | 4     | 4.8  | dB   |
| Noise Figure 2                                | NF2                   | $f = 2.2\text{ GHz}$                                                                       | —    | 4.1   | 4.9  |      |
| Isolation 1                                   | ISL1                  | $f = 1.0\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 36   | 41    | —    | dB   |
| Isolation 2                                   | ISL2                  | $f = 2.2\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 38   | 45    | —    |      |
| Input Return Loss 1                           | $RL_{in1}$            | $f = 1.0\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 9.5  | 13    | —    | dB   |
| Input Return Loss 2                           | $RL_{in2}$            | $f = 2.2\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 10   | 14.5  | —    |      |
| Output Return Loss 1                          | $RL_{out1}$           | $f = 1.0\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 12   | 15.5  | —    | dB   |
| Output Return Loss 2                          | $RL_{out2}$           | $f = 2.2\text{ GHz}$ , $P_{in} = -35\text{ dBm}$                                           | 12   | 15    | —    |      |
| Input 3rd Order Distortion Intercept Point 1  | IIP <sub>31</sub>     | $f_1 = 1\ 000\text{ MHz}$ , $f_2 = 1\ 001\text{ MHz}$                                      | —    | −9    | —    | dBm  |
| Input 3rd Order Distortion Intercept Point 2  | IIP <sub>32</sub>     | $f_1 = 2\ 200\text{ MHz}$ , $f_2 = 2\ 201\text{ MHz}$                                      | —    | −15.5 | —    |      |
| Output 3rd Order Distortion Intercept Point 1 | OIP <sub>31</sub>     | $f_1 = 1\ 000\text{ MHz}$ , $f_2 = 1\ 001\text{ MHz}$                                      | —    | +23.5 | —    | dBm  |
| Output 3rd Order Distortion Intercept Point 2 | OIP <sub>32</sub>     | $f_1 = 2\ 200\text{ MHz}$ , $f_2 = 2\ 201\text{ MHz}$                                      | —    | +18   | —    |      |
| 2nd Order Intermodulation Distortion          | IM <sub>2</sub>       | $f_1 = 1\ 000\text{ MHz}$ , $f_2 = 1\ 001\text{ MHz}$ ,<br>$P_{out} = -5\text{ dBm/ tone}$ | —    | 50    | —    | dBc  |
| 2nd Harmonic                                  | 2f <sub>0</sub>       | $f_0 = 1.0\text{ GHz}$ , $P_{out} = -15\text{ dBm}$                                        | —    | 70    | —    | dBc  |

Length of microstrip line :  $l_1 = 2.25$  mm  
 $l_2 = 2.75$  mm

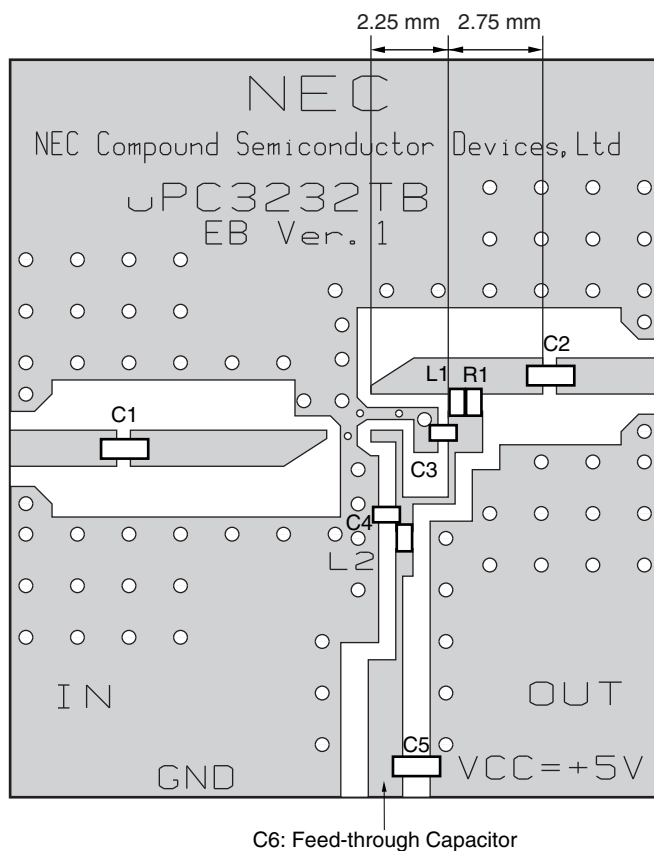
### COMPONENTS OF TEST CIRCUIT FOR MEASURING ELECTRICAL CHARACTERISTICS

|        | Type                   | Value        |
|--------|------------------------|--------------|
| R1     | Chip Resistance        | 560 $\Omega$ |
| L1     | Chip Inductor          | 47 nH        |
| L2     | Chip Inductor          | 68 nH        |
| C1     | Chip Capacitor         | 100 pF       |
| C2     | Chip Capacitor         | 33 pF        |
| C3, C4 | Chip Capacitor         | 1 000 pF     |
| C5     | Chip Capacitor         | 39 pF        |
| C6     | Feed-through Capacitor | 1 000 pF     |

The inductor has both DC and AC effects. In terms of DC, the inductor biases the output transistor with minimum voltage drop to output enable high level. In terms of AC, the inductor makes output-port impedance higher to get enough gain. In this case, large inductance and Q is suitable (Refer to the following page).

To obtain a flat gain from 100 MHz upwards, 1 000 pF capacitors are used in the test circuit. In the case of under 10 MHz operation, increase the value of coupling capacitor such as 10 000 pF. Because the coupling capacitors are determined by equation,  $C = 1/(2 \pi R f_c)$ .

ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



COMPONENT LIST

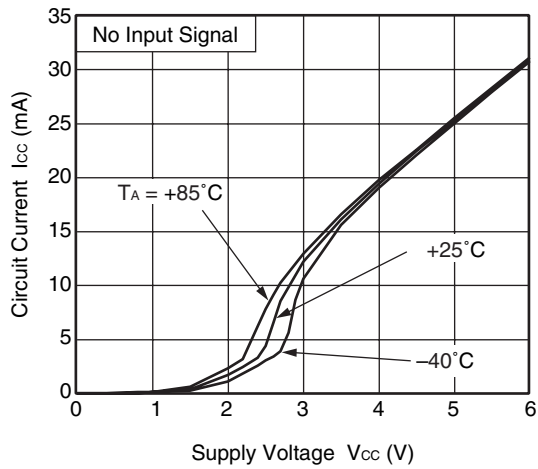
|        | Value    | Size                   |
|--------|----------|------------------------|
| R1     | 560 Ω    | 1005                   |
| L1     | 47 nH    | 1005                   |
| L2     | 68 nH    | 1005                   |
| C1     | 100 pF   | 1608                   |
| C2     | 33 pF    | 1608                   |
| C3, C4 | 1 000 pF | 1005                   |
| C5     | 39 pF    | 1608                   |
| C6     | 1 000 pF | Feed-through Capacitor |

Notes

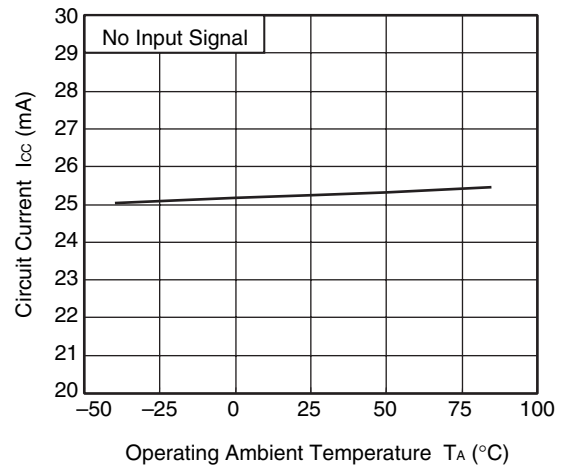
1. 19 × 21.46 × 0.51 mm double sided copper clad RO4003C (Rogers) board.
2. Back side: GND pattern
3. Au plated on pattern
4. ○○: Through holes
5. L1, L2: FDK's products

**TYPICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ ,  $V_{CC} = 5.0\text{ V}$ ,  $Z_S = Z_L = 50\ \Omega$ , unless otherwise specified)**

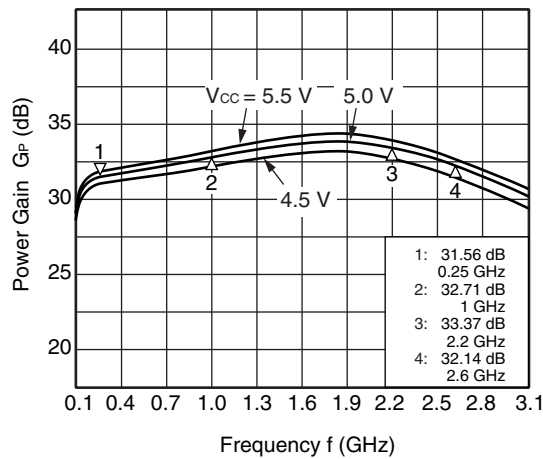
**CIRCUIT CURRENT vs. SUPPLY VOLTAGE**



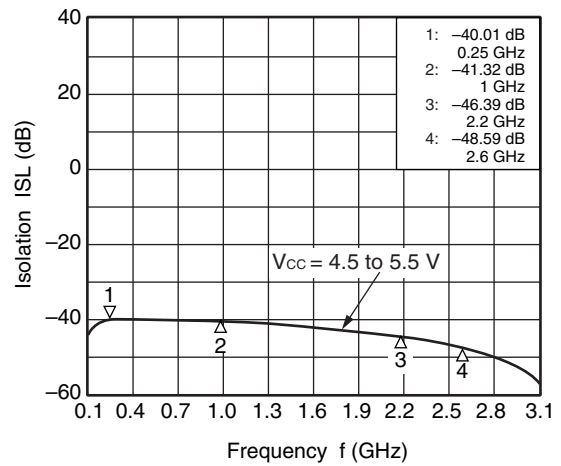
**CIRCUIT CURRENT vs. OPERATING AMBIENT TEMPERATURE**



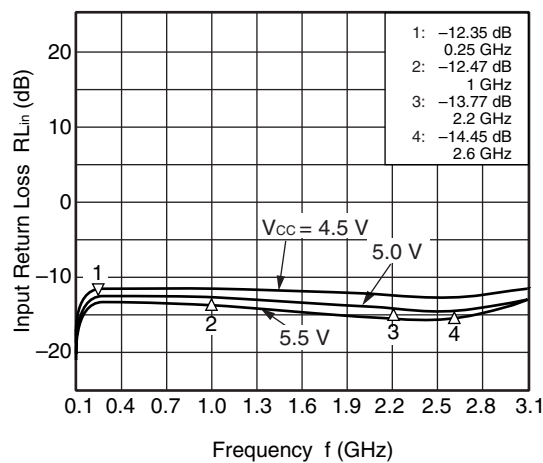
**POWER GAIN vs. FREQUENCY**



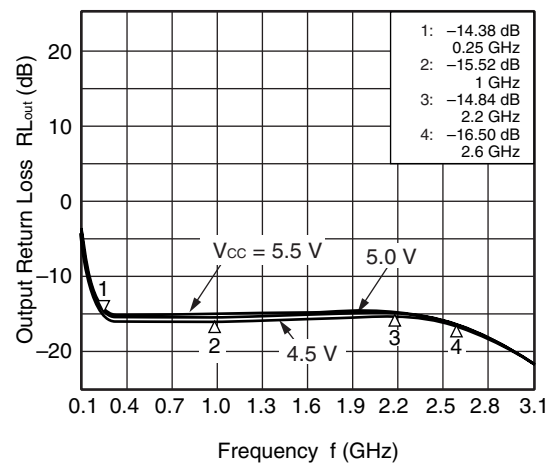
**ISOLATION vs. FREQUENCY**



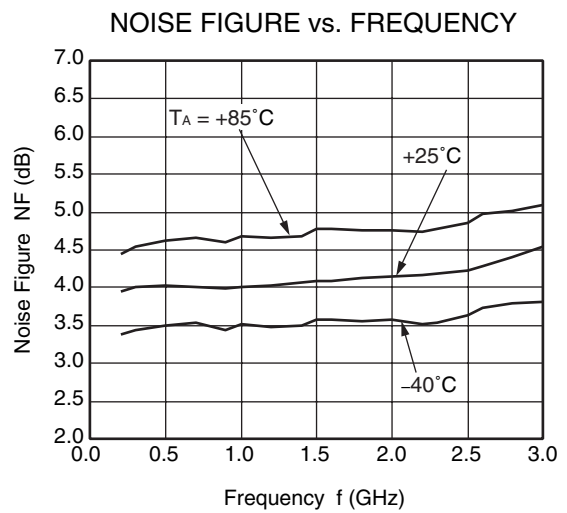
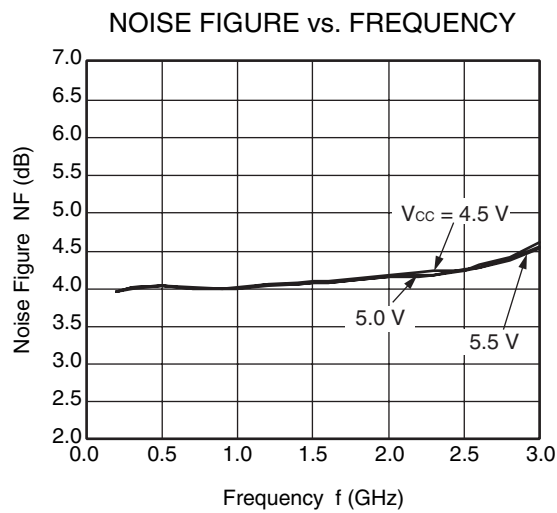
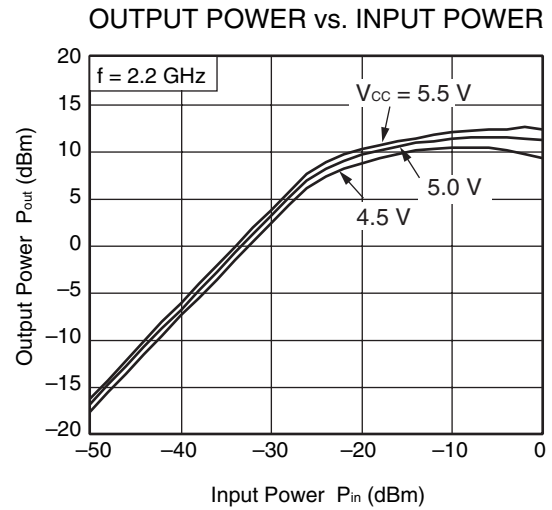
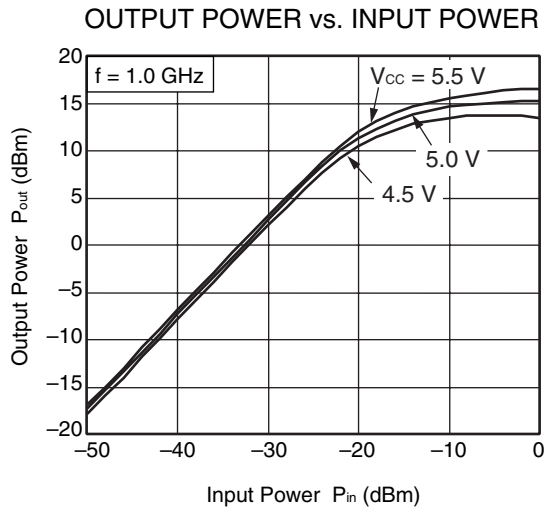
**INPUT RETURN LOSS vs. FREQUENCY**



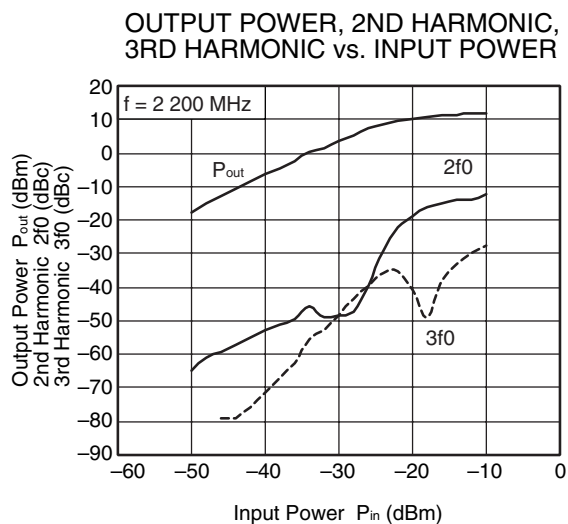
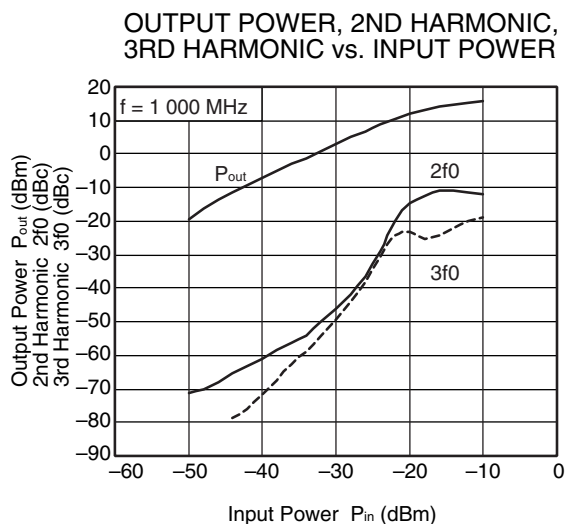
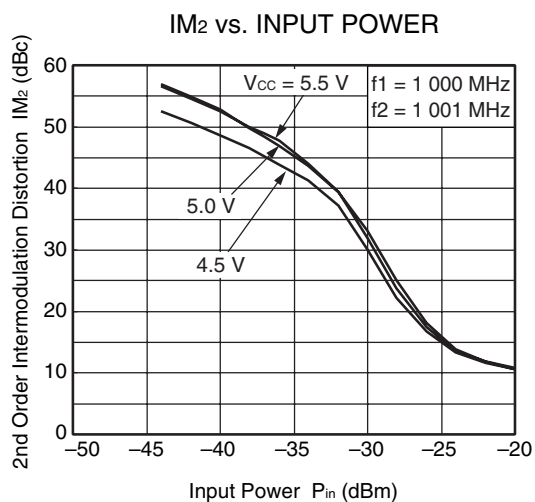
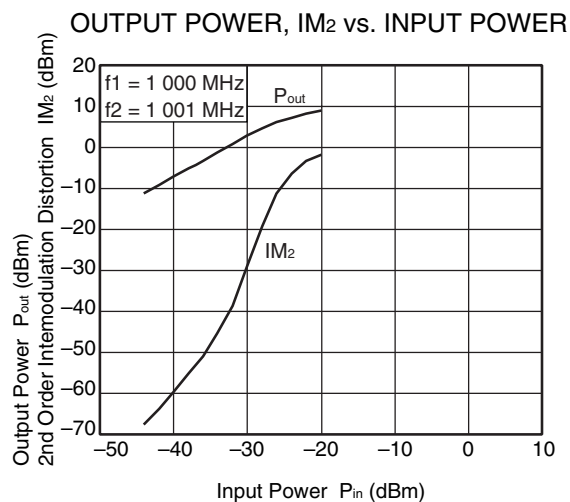
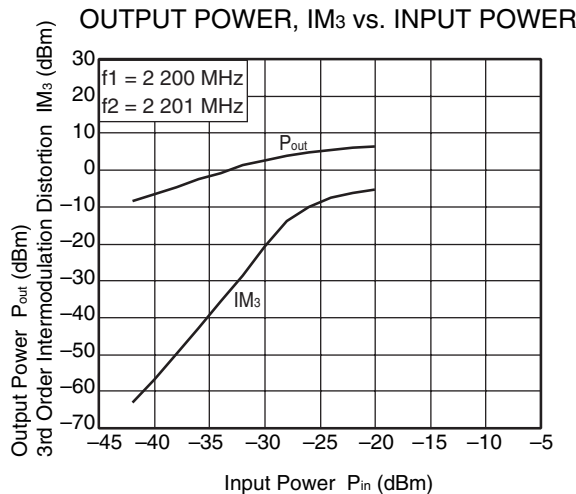
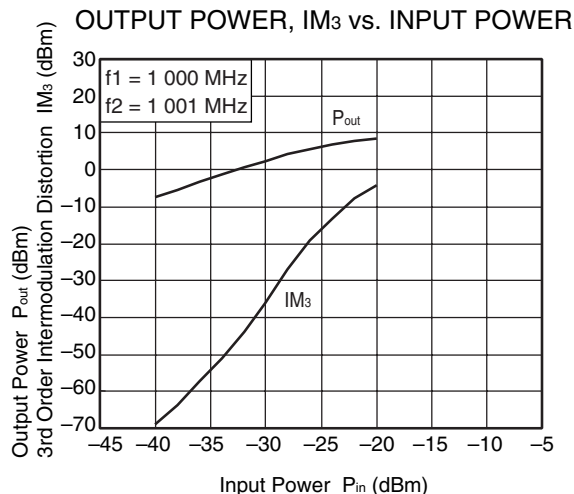
**OUTPUT RETURN LOSS vs. FREQUENCY**



**Remark** The graphs indicate nominal characteristics.



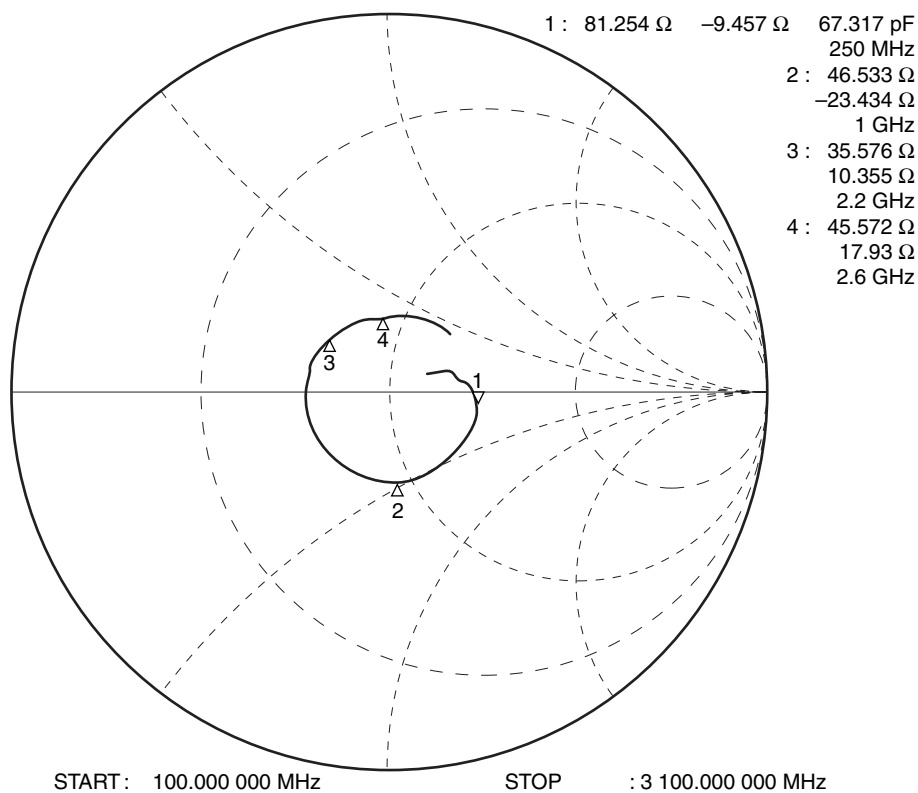
**Remark** The graphs indicate nominal characteristics.



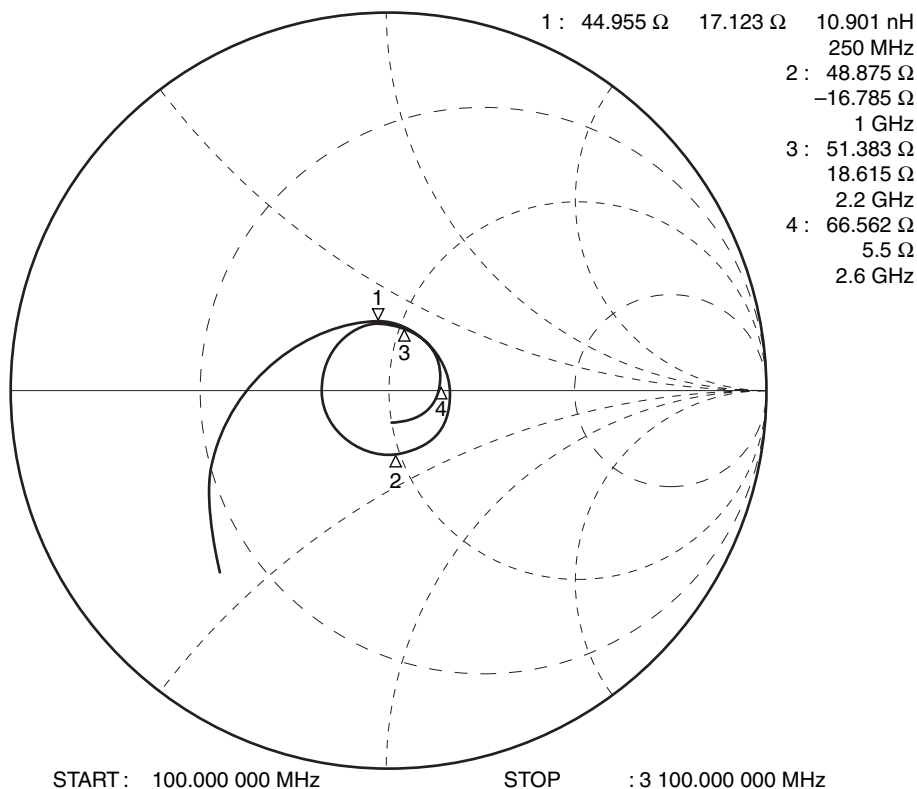
**Remark** The graphs indicate nominal characteristics.

S-PARAMETERS ( $T_A = +25^\circ\text{C}$ ,  $V_{DD} = V_{CC} = 5.0\text{ V}$ ,  $P_{in} = -35\text{ dBm}$ )

**S<sub>11</sub>—FREQUENCY**



**S<sub>22</sub>—FREQUENCY**



**S-PARAMETERS**

S-parameters/Noise parameters are provided on our web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

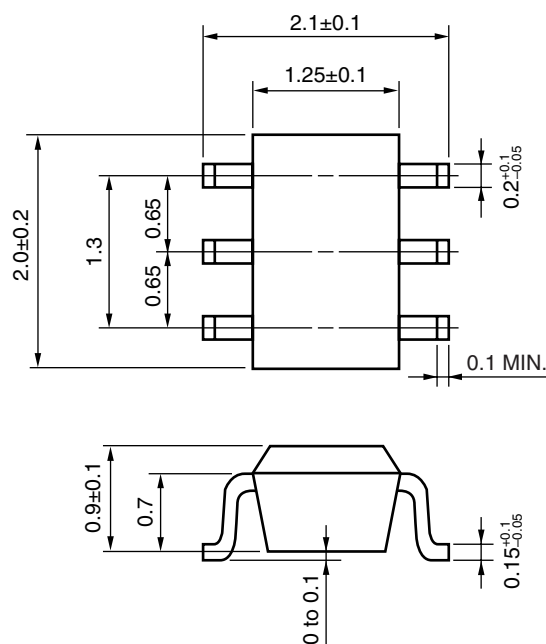
Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

URL <http://www.ncsd.necel.com/microwave/index.html>

PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)



**NOTES ON CORRECT USE**

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).  
All the ground terminals must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to the V<sub>CC</sub> line.
- (4) The inductor (L) must be attached between V<sub>CC</sub> and output pins. The inductance value should be determined in accordance with desired frequency.
- (5) The DC cut capacitor must be attached to input and output pin.

**RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

| Soldering Method | Soldering Conditions                                                                                                                                                                                                                                                                                                                                        | Condition Symbol |
|------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|
| Infrared Reflow  | Peak temperature (package surface temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Time at temperature of 220°C or higher : 60 seconds or less<br>Preheating time at 120 to 180°C : 120±30 seconds<br>Maximum number of reflow processes : 3 times<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below | IR260            |
| Wave Soldering   | Peak temperature (molten solder temperature) : 260°C or below<br>Time at peak temperature : 10 seconds or less<br>Preheating temperature (package surface temperature) : 120°C or below<br>Maximum number of flow processes : 1 time<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below                                                | WS260            |
| Partial Heating  | Peak temperature (terminal temperature) : 350°C or below<br>Soldering time (per side of device) : 3 seconds or less<br>Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below                                                                                                                                                                 | HS350            |

**Caution** Do not use different soldering methods together (except for partial heating).

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